

PSMN1R4-100CSF

NextPower 100 V, 1.35 mOhm, N-channel MOSFET in CCPAK1212i package

6 December 2024

Product data sheet

1. General description

NextPower 100 V, standard level gate drive MOSFET. Qualified to 175 °C and recommended for high power industrial and consumer applications.

2. Features and benefits

- Low Q_{rr} for higher efficiency and lower spiking
- 355 Amps I_{D(max)} continuous current rating
- Low Q_G × R_{DSon} FOM for high efficiency switching applications
- Strong avalanche energy rating (E_{as})
- Avalanche rated and 100% tested
- Ha-free and RoHS compliant CCPAK1212i package
- · Inverted package, suitable for top-side cooling

3. Applications

- · Battery protection
- · High power full and half-bridge configurations
- BLDC motor control
- OR-ing

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | I | Min | Тур | Max | Unit |
|-------------------|----------------------------------|---|---|-----|------|------|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | - | - | - | 100 | V |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u> | - | - | - | 355 | А |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | - | - | - | 935 | W |
| Static characte | eristics | | | | | ' | |
| R _{DSon} | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 11 | - | - | 1.07 | 1.35 | mΩ |
| Dynamic chara | acteristics | | | | | ' | ' |
| Q_{GD} | gate-drain charge | I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u> | | 14 | 46 | 106 | nC |
| Source-drain o | diode | | | | | ' | |
| Q _r | recovered charge | $I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 17$ | - | - | 74 | - | nC |



5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|-----------------------|----------------|
| 1 | S | source | | |
| 2 | S | source | | |
| 3 | S | source | 12 11 10 9 8 7 | |
| 4 | S | source | | |
| 5 | S | source | | |
| 6 | G | gate |] U | D |
| 7 | D | drain | | |
| 8 | D | drain | | G T |
| 9 | D | drain | | mbb076 S |
| 10 | D | drain | 1 2 3 4 5 6 | |
| 11 | D | drain | sot8005a_sv | |
| 12 | D | drain | CCPAK1212i (SOT8005A) | |
| mb | D | mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|----------------|------------|--|----------|
| | Name | Description | Version |
| PSMN1R4-100CSF | CCPAK1212i | Plastic, surface mounted copper clip package (CCPAK1212i); 12 terminals; 2.0 mm pitch, 12 mm × 12 mm × 2.5 mm body | SOT8005A |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|----------------|--------------|
| PSMN1R4-100CSF | XP1F4S10C |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). T_i = 25 °C unless otherwise stated.

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|----------------------|--|---|-----|-----|------|------|
| V _{DS} | drain-source voltage | 25 °C ≤ T _j ≤ 175 °C | | - | 100 | V |
| V_{DGR} | drain-gate voltage | 25 °C ≤ T _j ≤ 175 °C; R _{GS} = 20 kΩ | | - | 100 | V |
| V _{GS} | gate-source voltage | | | -20 | 20 | V |
| P _{tot} | total power dissipation | T _{mb} = 25 °C; <u>Fig. 1</u> | | - | 935 | W |
| I _D | drain current | V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u> | | - | 355 | Α |
| | | V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u> | | - | 355 | Α |
| I _{DM} | peak drain current | pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3 | | - | 2195 | Α |
| T _{stg} | storage temperature | | | -55 | 175 | °C |
| T _j | junction temperature | | | -55 | 175 | °C |
| $T_{sld(M)}$ | peak soldering temperature | | | - | 260 | °C |
| Source-drain d | liode | | _ | | • | |
| ls | source current | T _{mb} = 25 °C | | - | 355 | Α |
| lsм | peak source current | pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \degree C$ | | - | 2195 | Α |
| Avalanche rug | gedness | | | | • | _ |
| E _{DS(AL)S} | non-repetitive drain- source avalanche energy | I_D = 99 A; $V_{sup} \le 100$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 175 μs; Fig. 4 | [1] | - | 1130 | mJ |
| I _{AS} | non-repetitive avalanche current | $V_{sup} = 100 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \Omega; Fig. 4$ | [1] | - | 99 | Α |

[1] Protected by 100% test

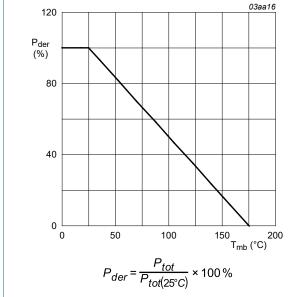
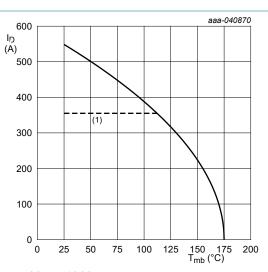
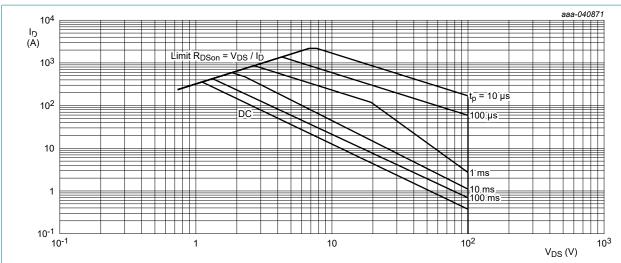


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



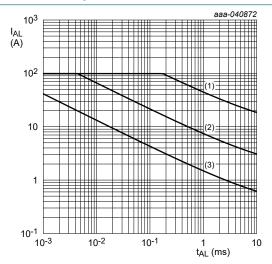
 $V_{GS} \ge 10 \text{ V}$ (1) 355 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature



T_{mb} = 25 °C; I_{DM} is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



(1) $T_{j \text{ (init)}}$ = 25 °C; (2) $T_{j \text{ (init)}}$ = 150 °C; (3) Repetitive Avalanche

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|------------|-----|-------|------|------|
| R _{th(j-mb)} | thermal resistance from junction to mounting base | Fig. 5 | - | 0.123 | 0.16 | K/W |
| R _{th(j-a)} | thermal resistance from | Fig. 6 | - | 58 | - | K/W |
| junction t | junction to ambient | Fig. 7 | - | 29 | - | K/W |

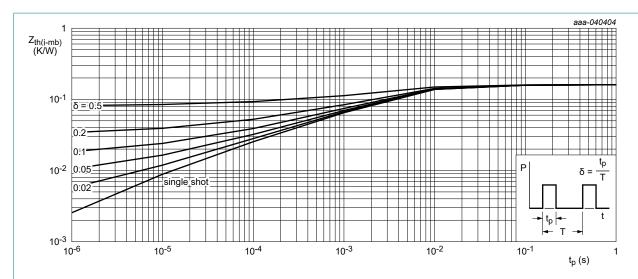
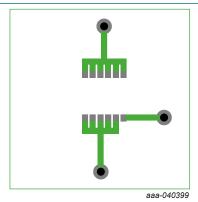
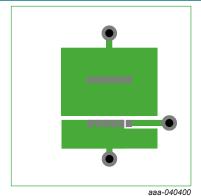


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration



70 µm thick copper on FR4 board

Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient



Copper area 25.4 mm square; 70 μ m thick on FR4 board

Fig. 7. PCB layout for thermal resistance from junction to ambient

10. Characteristics

Table 7. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------------|--|---|-------|-------|-------|------|
| Static charac | cteristics | | | | | 1 |
| V _{(BR)DSS} | drain-source | I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C | 100 | - | - | V |
| | breakdown voltage | I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C | 90 | - | - | V |
| V _{GS(th)} | gate-source threshold | I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C | 2 | 3.1 | 4 | V |
| | voltage | I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 175 °C | - | 1.61 | - | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$ | - | 3.7 | - | V |
| $\Delta V_{GS(th)}/\Delta T$ | gate-source threshold voltage variation with temperature | 25 °C ≤ T _j ≤ 150 °C | - | -9.4 | - | mV/K |
| I _{DSS} | drain leakage current | V _{DS} = 100 V; V _{GS} = 0 V; T _j = 25 °C | - | 0.05 | 1.6 | μA |
| | | V _{DS} = 100 V; V _{GS} = 0 V; T _i = 125 °C | - | 35 | 160 | μA |
| I _{GSS} | gate leakage current | V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C | - | 2 | 100 | nA |
| | | V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C | - | 2 | 100 | nA |
| R _{DSon} | drain-source on-state resistance | V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11 | - | 1.07 | 1.35 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 12 | - | 1.7 | 2.2 | mΩ |
| | | V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 12 | - | 2.4 | 3.1 | mΩ |
| | | V _{GS} = 7 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 11</u> | - | 1.36 | 2.04 | mΩ |
| R_G | gate resistance | f = 1 MHz; T _j = 25 °C | 0.51 | 1.02 | 2.05 | Ω |
| Dynamic cha | aracteristics | 1 | | | | |
| Q _{G(tot)} | total gate charge | I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V; T _j = 25 °C; <u>Fig. 13</u> ; <u>Fig. 14</u> | 128 | 255 | 383 | nC |
| | | I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; T _j = 25 °C | - | 228 | - | nC |
| Q _{GS} | gate-source charge | I _D = 25 A; V _{DS} = 50 V; V _{GS} = 10 V; | 46 | 76.5 | 107 | nC |
| Q _{GS(th)} | pre-threshold gate- source charge | T _j = 25 °C; <u>Fig. 13; Fig. 14</u> | - | 51 | - | nC |
| Q _{GS(th-pl)} | post-threshold gate- source charge | | - | 25.4 | - | nC |
| Q_{GD} | gate-drain charge | | 14 | 46 | 106 | nC |
| $V_{GS(pl)}$ | gate-source plateau voltage | I _D = 25 A; V _{DS} = 50 V; T _j = 25 °C; Fig. 13; Fig. 14 | - | 4.4 | - | V |
| C _{iss} | input capacitance | $V_{DS} = 50 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ | 10901 | 18168 | 25436 | pF |
| C _{oss} | output capacitance | T _j = 25 °C; <u>Fig. 15</u> | 2494 | 4157 | 6652 | pF |
| C _{rss} | reverse transfer capacitance | | 9 | 92 | 239 | pF |
| t _{d(on)} | turn-on delay time | $V_{DS} = 50 \text{ V}; R_L = 2 \Omega; V_{GS} = 10 \text{ V};$ | - | 67 | - | ns |
| t _r | rise time | $R_{G(ext)} = 5 \Omega$; $T_j = 25 °C$ | - | 63 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 157 | - | ns |
| t _f | fall time | | - | 84 | - | ns |
| Source-drair | n diode | | I | 1 | 1 | |
| V _{SD} | source-drain voltage | I _S = 25 A; V _{GS} = 0 V; T _i = 25 °C; <u>Fig. 16</u> | _ | 0.76 | 1 | V |

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------|------------------|---|-----|-----|-----|------|
| t _{rr} | | $I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$ | - | 62 | - | ns |
| Q _r | recovered charge | V _{DS} = 50 V; T _j = 25 °C; <u>Fig. 17</u> | - | 74 | - | nC |

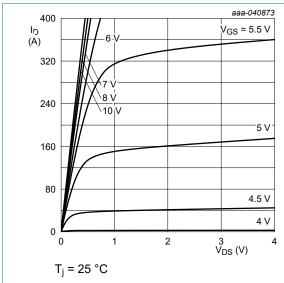


Fig. 8. Output characteristics; drain current as a function of drain-source voltage; typical values

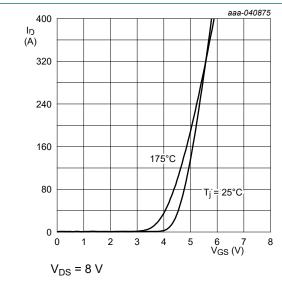


Fig. 10. Transfer characteristics; drain current as a function of gate-source voltage; typical values

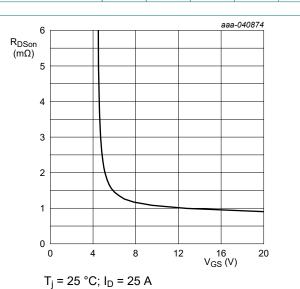


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

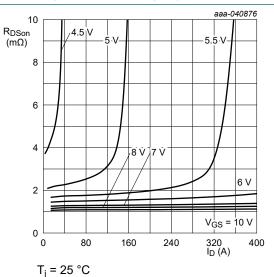


Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

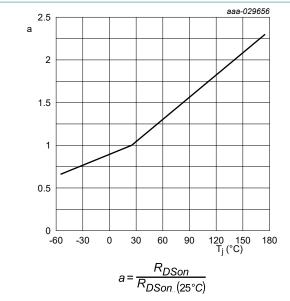


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

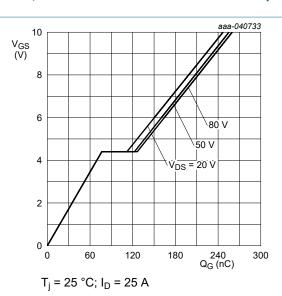


Fig. 13. Gate-source voltage as a function of gate charge; typical values

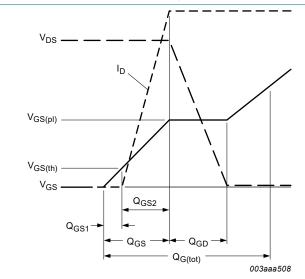
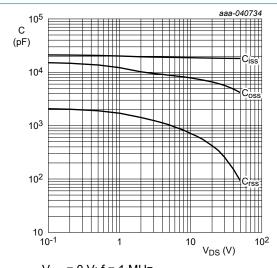


Fig. 14. Gate charge waveform definitions



 $V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}$

Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

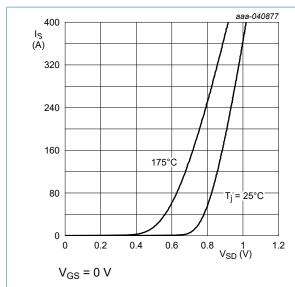


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

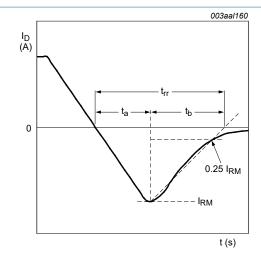
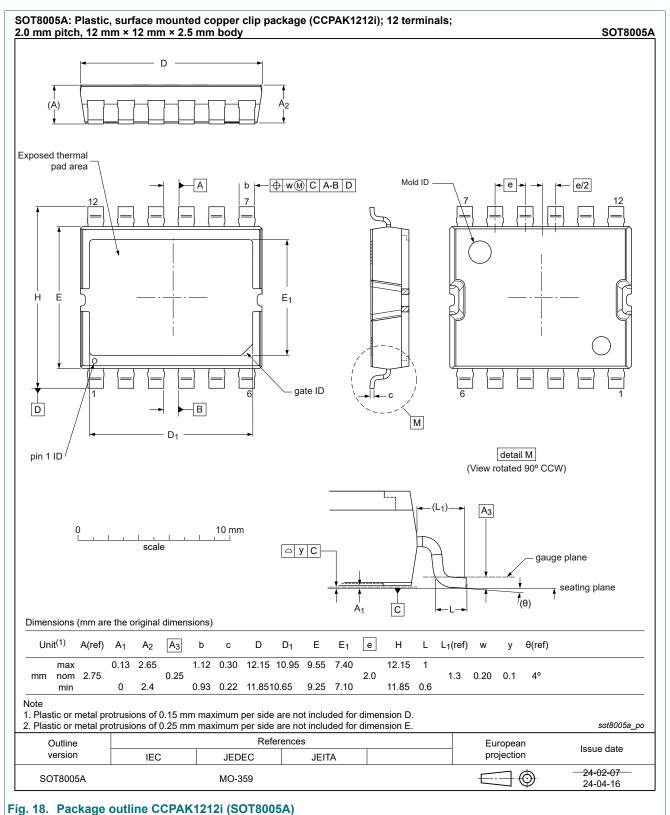
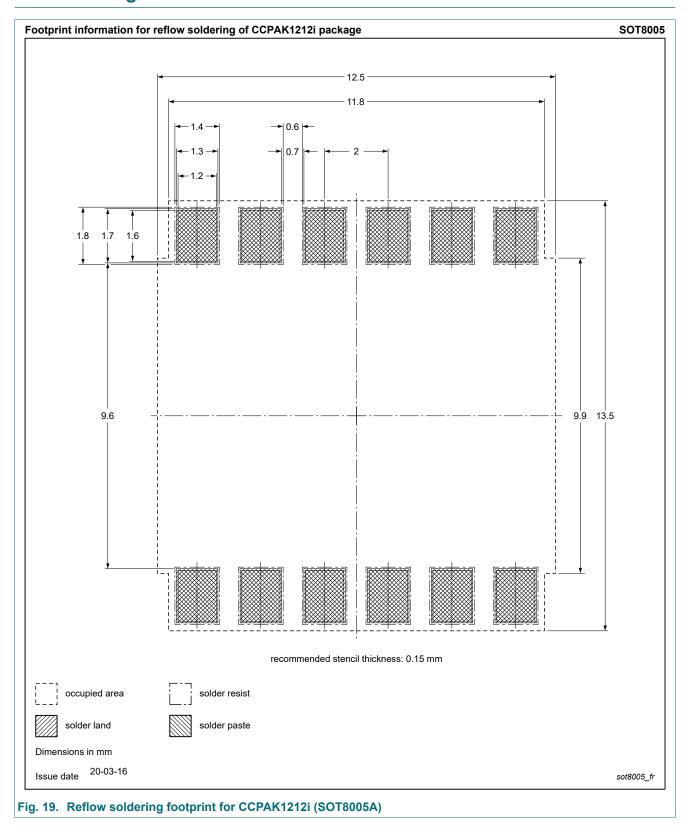


Fig. 17. Reverse recovery timing definition

11. Package outline



12. Soldering



13. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
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Contents

| 1. | General description | 1 |
|-----|-------------------------|----|
| 2. | Features and benefits | 1 |
| 3. | Applications | 1 |
| 4. | Quick reference data | 1 |
| 5. | Pinning information | 2 |
| 6. | Ordering information | 2 |
| 7. | Marking | 2 |
| | Limiting values | |
| | Thermal characteristics | |
| 10 | . Characteristics | 6 |
| 11. | . Package outline | 10 |
| 12 | . Soldering | 11 |
| | . Legal information | |

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13 / 13

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